

T1235H, T1250H

High temperature 12 A Snubberless™ Triacs

Features

- Medium current Triac
- 150 °C max. T_i turn-off commutation
- Low thermal resistance with clip bonding
- Very high 3 quadrant commutation capability
- Packages are RoHS (2002/95/EC) compliant
- UL certified (ref. file E81734)

Applications

Especially designed to operate in high power density or universal motor applications such as vacuum cleaner and washing machine drum motor, these 12 A Triacs provide a very high switching capability up to junction temperatures of 150 °C.

The heatsink can be reduced, compared to traditional Triacs, according to the high performance at given junction temperatures.

Description

Available in through-hole or surface mount packages, the T1235H and T1250H Triac series are suitable for general purpose mains power ac switching.

By using an internal ceramic pad, the T12xxH-6l provides voltage insulation (rated at 2500 V rms).

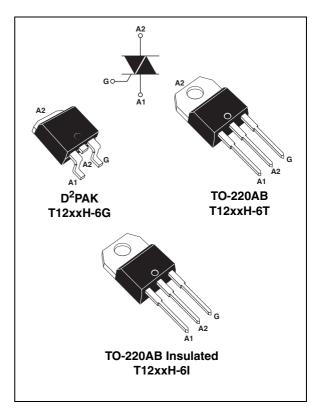


Table 1. Device summary

Symbol	Value	Unit
I _{T(RMS)}	12	Α
V_{DRM}/V_{RRM}	600	V
I _{GT}	35 or 50	mA

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Characteristics T1235H, T1250H

1 Characteristics

Table 2. Absolute maximum ratings

Symbol	Parameter			Value	Unit	
	On state rms surrent (full sine ways)	D ² PAK, TO-220AB $T_c = 130 ^{\circ}\text{C}$		12	^	
I _{T(RMS)}	On-state rms current (full sine wave)	TO-220AB Ins	T _c = 120 °C	12	Α	
	Non repetitive surge peak on-state	F = 50 Hz	t = 20 ms	120	•	
I _{TSM}	current (full cycle, T _j initial = 25 °C)	F = 60 Hz	t = 16.7 ms	126	Α	
l ² t	I ² t Value for fusing	t _p = 10 ms		95	A^2s	
dI/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r \le 100 \text{ ns}$	F = 120 Hz	T _j = 150 °C	50	A/μs	
V _{DSM} /V _{RSM}	Non repetitive surge peak off-state voltage	t _p = 10 ms	T _j = 25 °C	V _{DRM} /V _{RRM} + 100	V	
I _{GM}	Peak gate current	t _p = 20 μs	T _j = 150 °C	4	Α	
P _{G(AV)}	Average gate power dissipation $T_j = 150 ^{\circ}\text{C}$			1	W	
T _{stg} T _j	Storage junction temperature range Operating junction temperature range			- 40 to + 150 - 40 to + 150	Ô	

Table 3. Electrical characteristics ($T_j = 25$ °C, unless otherwise specified)

Symbol	Test conditions	Quadrant		Value		Unit
Symbol	rest conditions			T1235H T1250H		Offic
I _{GT} ⁽¹⁾	$V_D = 12 \text{ V, R}_L = 33 \Omega$	I - II - III	MAX.	35	50	mA
V _{GT}	VD = 12 V, 11L = 33 32	1 - 11 - 111	MAX.	1.0		V
V_{GD}	$V_D = V_{DRM}, R_L = 3.3 \text{ k}\Omega$ I - II - III		MIN.	0.15		V
I _H ⁽²⁾	I _T = 500 mA		MAX.	35	75	mA
	I _G = 1.2 I _{GT}	I - III	MAX.	50	90	- mA
IL		II		80	110	
dV/dt (2)	V _D = 67% V _{DRM,} gate open, T _j = 150 °C		MIN.	1000	1500	V/µs
(dl/dt)c (2)	Without snubber, T _j = 150 °C		MIN.	16	21	A/ms

^{1.} minimum $I_{\mbox{\footnotesize GT}}$ is guaranted at 20% of $I_{\mbox{\footnotesize GT}}$ max.

^{2.} for both polarities of A2 referenced to A1.

T1235H, T1250H Characteristics

Table 4. Static characteristics

Symbol	Test conditions			Value	Unit
V _T ⁽¹⁾	I _{TM} = 17 A, t _p = 380 μs	T _j = 25 °C	MAX.	1.5	٧
V _{t0} (1)	Threshold voltage	T _j = 150 °C	MAX.	0.80	V
R _d ⁽¹⁾	Dynamic resistance	T _j = 150 °C	MAX.	30	mΩ
$V_{DRM} = V_{RRM}$ I_{DRM} I_{RRM} $V_D/V_R = 400 V (at peak not be considered as a constant of the cons$	V - V	T _j = 25 °C	MAX.	5	μΑ
	VDRM = VRRM	T _j = 150 °C	MAX.	3.9	
	V _D /V _R = 400 V (at peak mains voltage)	T _j = 150 °C	MAX.	3.2	mA
	V _D /V _R = 200 V (at peak mains voltage)	T _j = 150 °C	MAX.	2.7	

^{1.} for both polarities of A2 referenced to A1

Table 5. Thermal resistance

Symbol	Parameter			Value	Unit
В	lunation to soon (AC)		D ² PAK / TO-220AB	1.4	
R _{th(j-c)}	Junction to case (AC)		TO-220AB Ins	3.3	0000
R _{th(j-a)} Junction to ambient	lunation to ombiont	$S = 1 \text{ cm}^2$	D ² PAK	45	°C/W
	Junction to ambient		TO-220AB / TO-220AB Ins	60	-

^{2.} $t_p = 380 \mu s$

Characteristics T1235H, T1250H

Figure 1. Maximum power dissipation versus Figure 2. On-state rms current versus case on-state rms current (full cycle) temperature (full cycle)

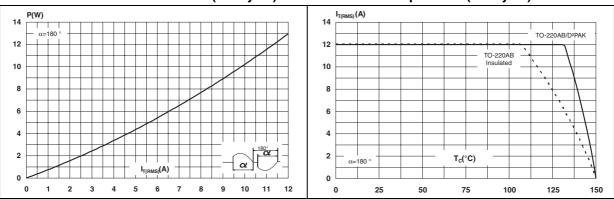


Figure 3. On-state rms current versus ambient temperature

Figure 4. Variation of thermal impedance versus pulse duration

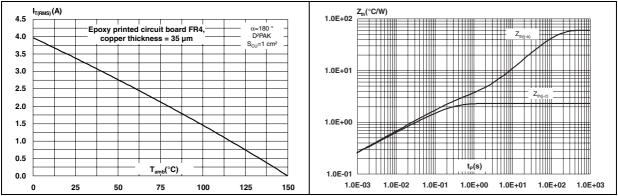
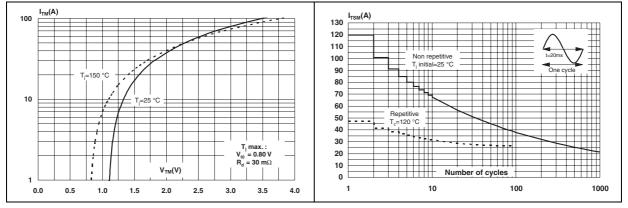


Figure 5. On-state characteristics (maximum values)

Figure 6. Surge peak on-state current versus number of cycles



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T1235H, T1250H Characteristics

Figure 7. Non-repetitive surge peak on-state Figure 8. Relative variation of I_{GT} , I_{L} vs current for a sinusoidal pulse with junction temperature (typical values)

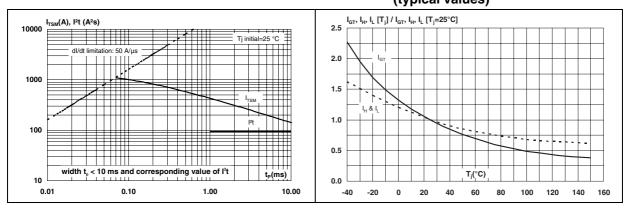


Figure 9. Relative variation of critical rate of Figure 10. decrease of main current (dl/dt)c versus reapplied (dV/dt)c

Figure 10. Relative variation of critical rate of decrease of main current versus junction temperature

(dl/dt), [T,] / (dl/dt), [T,=150°C]

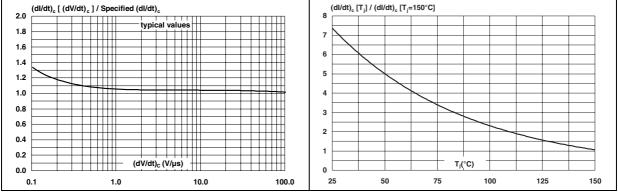
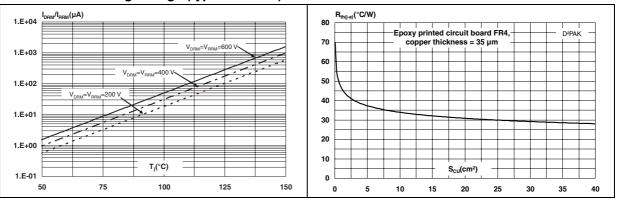


Figure 11. Leakage current versus junction temperature for different values of blocking voltage (typical values)

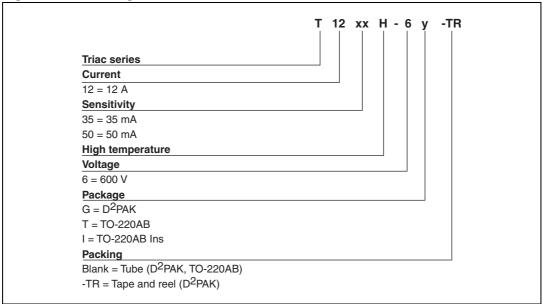
Figure 12. Variation of thermal resistance junction to ambient versus copper surface under tab



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2 Ordering information scheme

Figure 13. Ordering information scheme



T1235H, T1250H Package information

3 Package information

- Epoxy meets UL94, V0
- Recommended torque 0.4 to 0.6 N⋅m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

Table 6. D²PAK dimensions

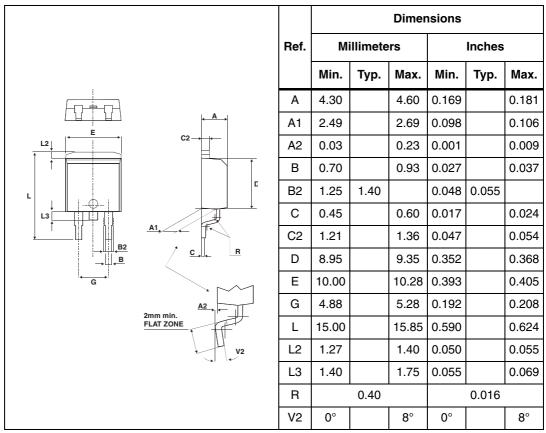
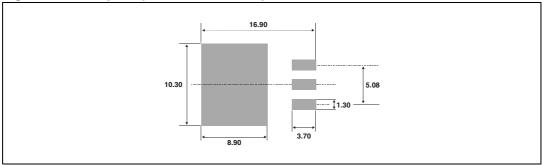


Figure 14. Footprint (dimensions in mm)



Package information T1235H, T1250H

Dimensions Ref. Millimeters Inches Min. Typ. Max. Min. Тур. Max. 15.20 15.90 0.598 0.625 Α 0.147 a1 3.75 В a2 13.00 14.00 0.511 0.551 Ø١ В 10.00 10.40 0.393 0.409 b1 0.61 0.88 0.024 0.034 0.051 b2 1.23 1.32 0.048 14 С 4.40 4.60 0.173 0.181 13 с1 0.49 0.70 0.019 0.027 c2 c2 2.40 2.72 0.094 0.107 a2 2.40 2.70 0.094 0.106 е F 6.20 6.60 0.244 0.259 ØΙ 3.75 3.85 0.147 0.151 0.661 14 15.80 16.40 16.80 0.622 0.646 L 2.65 2.95 0.104 0.116 12 1.14 0.044 0.066 1.70 13 1.14 1.70 0.044 0.066 Μ 2.60 0.102

Table 7. TO-220AB and TO-220AB Ins dimensions

4 Ordering information

Table 8. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
T12xxH-6G	T12xxH 6G	D ² PAK	1.5 g	50	Tube
T12xxH-6G-TR	T12xxH 6G	D ² PAK	1.5 g	1000	Tape and reel
T12xxH-6T	T12xxH 6T	TO-220AB	2.3 g	50	Tube
T12xxH-6l	T12xxH 6l	TO-220AB Ins	2.3 g	50	Tube

5 Revision history

Table 9. Document revision history

Date	Revision	Changes	
17-Apr-2007	1	First issue.	
20-Sep-2011	2	Updated: Features, Description and Figure 2.	

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